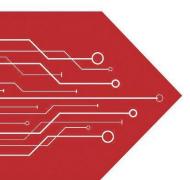
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Product data sheet

www.msksemi.com







FEATURE

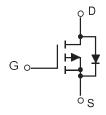
- High dense cell design for extremely low R_{DS(ON)}.
- Exceptional on-resistance and maximum DC current capability

APPLICATION

- Load/Power Switching
- Interfacing Switching

SOT-23	.3L
1. GATE	1 4
2. SOURCE	-
3. DRAIN	

Equivalent Circuit



V _{(BR)DSS}	R _{DS(on)} MAX	I _D
-30 V	65mΩ@-10V	
	75mΩ@-4.5V	-4.2A
	90mΩ@-2.5V	

Maximum ratings (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	-4.2	Α
Power Dissipation	P _D	350	mW
Thermal Resistance from Junction to Ambient (t<5s)	R _{θJA}	357	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55~+150	°C



MOSFET ELECTRICAL CHARACTERISTICS

T_a=25 °C unless otherwise specified

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Off characteristics	1			•		
Drain-source breakdown voltage	V(BR)DSS	V _{GS} = 0V, I _D =-250μA	-30			V
Zero gate voltage drain current	IDSS	V _{DS} =-24V,V _{GS} = 0V			-1	μA
Gate-source leakage current	Igss	V _{GS} =±12V, V _{DS} = 0V			±100	nA
On characteristics						
Dutana		V _{GS} =-10V, I _D =-4.2A		50	65	mΩ
Drain-source on-resistance	RDS(on)	V _{GS} =-4.5V, I _D =-4A		60	75	mΩ
(note 1)		V _{GS} =-2.5V,I _D =-1A		75	90	mΩ
Forward tranconductance (note 1)	g FS	V _{DS} =-5V, I _D =-5A	7			S
Gate threshold voltage	VGS(th)	V _{DS} =V _{GS} , I _D =-250μA	-0.7	-0.9	-1.3	V
Dynamic characteristics (note 2)				•		
Input capacitance	Ciss			954		pF
Output capacitance	Coss	V _{DS} =-15V,V _{GS} =0V,f =1MHz		115		pF
Reverse transfer capacitance	Crss			77		pF
Switching characteristics (note 2)	11.	,	'			
Turn-on delay time	td(on)				6.3	ns
Turn-on rise time	tr	V _{GS} =-10V,V _{DS} =-15V,			3.2	ns
Turn-off delay time	td(off)	R_L =3.6 Ω , R_{GEN} =6 Ω			38.2	ns
Turn-off fall Time	tf				12	ns
Drain-source diode characteristic	s and maxi	mum ratings				
Diode forward voltage (note 1)	V_{SD}	I _S =-1A,V _{GS} =0V			-1	V

Note:

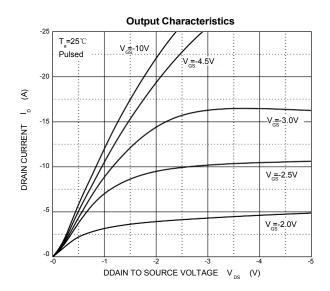
- 1. Pulse Test: Pulse width≤300µs, duty cycle≤2%.
- 2. These parameters have no way to verify.

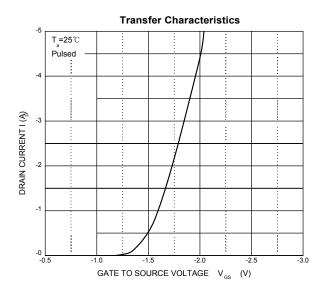


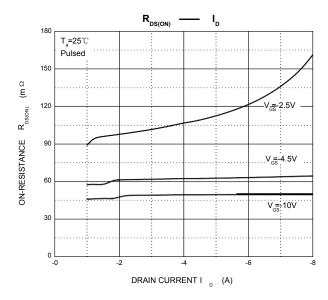


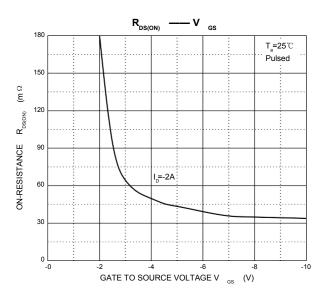


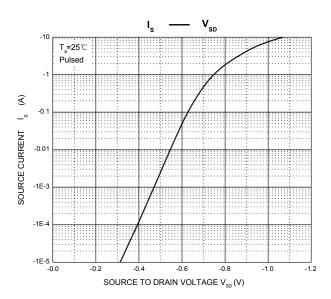
Typical Characteristics





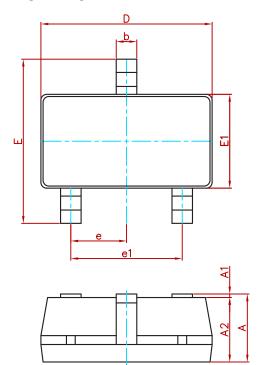


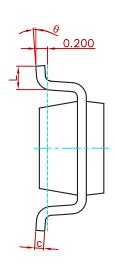






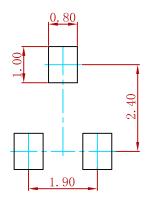
PACKAGE MECHANICAL DATA





Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(BSC)		0.037((BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
Α	0°	8°	0°	8°

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
AO3401MI-MS	SOT-23-3L	3000



Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.

单击下面可查看定价,库存,交付和生命周期等信息

>>MSKSEMI (美森科)